NSN 5961-01-007-5845

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-007-5845 **Inclosure Material:** Glass **Overall Length:** Between 0.240 inches and 0.290 inches **Terminal Length:** Between 0.115 inches and 0.185 inches **Overall Height:** Between 0.030 inches and 0.070 inches **Overall Width:** Between 0.120 inches and 0.265 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Features Provided:** Burn in **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage/static/emitter open all transistor and 60.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 600.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 1.4 watts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 6 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No